

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

### IXFH18N60X

### • FEATURES

- Static drain-source on-resistance:  $R_{DS}(on) \le 230m\Omega@V_{GS}=10V$
- · Fully characterized avalanche voltage and current
- 100% Avalanche Tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

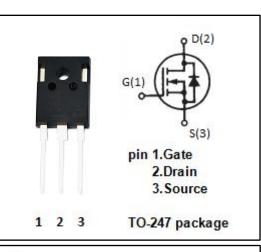
### APPLICATION

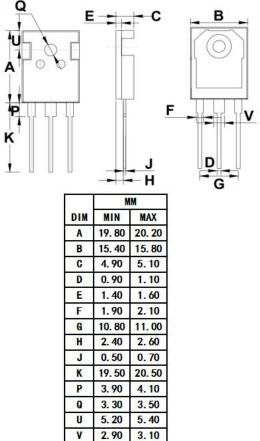
- Switched mode power supplies
- DC-DC converters

### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	600	V			
V <sub>GS</sub>	Gate-Source Voltage	±30	V			
Ι <sub>D</sub>	Drain Current-Continuous	18	А			
I <sub>DM</sub>	Drain Current-Single Pulsed	36	А			
PD	Total Dissipation @T <sub>c</sub> =25°C	320	W			
Tj	Operating Junction Temperature	-55~150	°C			
T <sub>stg</sub>	Storage Temperature	-55~150	°C			
THERMAL CHARACTERISTICS						
SYMBOL	PARAMETER	МАХ	UNIT			

Junction-to-case thermal resistance





Rth(j-c)

°C/W

0.39

1



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V; ID = 250 μ A	600		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 1.5mA	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 9A		230	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = ±30V; $V_{DS}$ =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		10	μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 125°C		500	
Vsd	Diode forward voltage	I <sub>F</sub> = 18A; V <sub>GS</sub> = 0V		1.4	V

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